

DESCRIPTION

The ULN2803/2804 series are high-voltage, high-current darlington arrays comprised of eight NPN darlington pairs. All units feature integral clamp diodes for switching inductive loads.

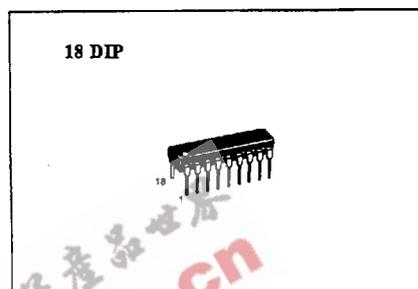
FEATURES

- Output current.....500mA
- High Sustaining Voltage.....50V Min.
- Output Clamp Diode
- Inputs Compatible With Various Types of Logic

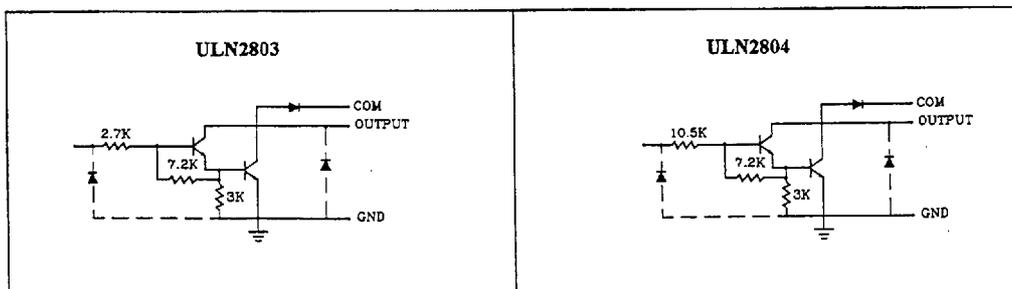
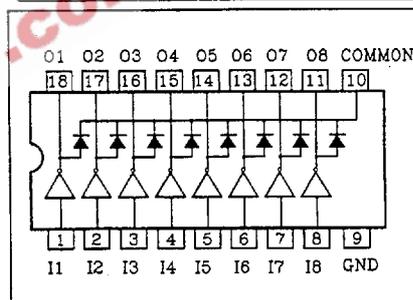
Type	Input Resistor	Designation
ULN2803	2.7K Ω	TTL, 5V C - MOS
ULN2804	10.5K Ω	6 ~ 15V P -MOS, C -MOS

MAXIMUM RATING(Ta=25 $^{\circ}$ C unless otherwise)

Characteristic	Symbol	Rating	Unit
Output Sustaining Voltage	V _{CE(sus)}	50	V
Output Current	I _{OUT}	500	mA
Input Voltage	V _{IN}	-0.5~+30	V
Input Current	I _{IN}	25	mA
Clamp Diode	Reverse Voltage	V _R	50 V
	Forward Current	I _F	500 mA
GND Terminal Current	I _{GND}	3.2	A
Power Dissipation	P _D	1.47	W
Operating Temperature	T _{opr}	-40~85	$^{\circ}$ C
Storage Temperature	T _{stg}	-55~150	$^{\circ}$ C



PIN CONNECTION (TOP VIEW)



RECOMMENDED OPERATING CONDITIONS(Ta=-40-85 °C)

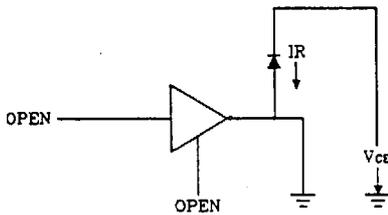
CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Output Sustaining Voltage	V _{CE(SUS)}		0	-	50	V
Output Current	I _{OUT}	T _{PW} =25mS,DF=8%, 8 Circuits	0	-	400	mA
		T _{PW} =25mS,DF=25% 8 Circuits	0	-	200	
Input Voltage	V _{IN}		0	-	30	V
Clamp Diode Reverse Voltage	V _R		-	-	50	V
Clamp Diode Forward Current	I _F		-	-	400	mA
Power Dissipation	P _D		-	-	0.52	W

ELECTRICAL CHARACTERISTICS(Ta=25 °C unless otherwise noted)

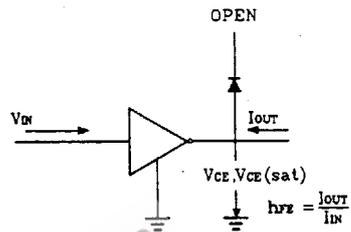
CHARACTERISTIC	SYMBOL	TEST CIRCUIT	CONDITION	MIN.	TYP.	MAX.	UNIT	
Output leak Current	I _{CEX}	1	V _{CE} =50V, Ta=25 °C	-	-	50	μ A	
			V _{CE} =50V, Ta=85 °C	-	-	100		
			V _{CE} =50V, V _{IN} =1V	-	-	500		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	2	I _{OUT} =350mA, I _{IN} =500 μ A	-	1.3	1.6	V	
			I _{OUT} =200mA, I _{IN} =350 μ A	-	1.1	1.3		
			I _{OUT} =100mA, I _{IN} =250 μ A	-	0.9	1.1		
Input Current	I _{IN(on)}	3	V _{IN} =3.85V	-	0.93	1.35	mA	
			V _{IN} =5V	-	0.35	0.5		
			V _{IN} =12V	-	1.0	1.45		
Input Voltage	V _{IN(ON)}	5	I _{OUT} =500 μ A, Ta=85 °C	50	65	-	μ A	
			V _{CE} =2V, I _{OUT} =200mA	-	-	2.4		V
			V _{CE} =2V, I _{OUT} =250mA	-	-	2.7		
			V _{CE} =2V, I _{OUT} =300mA	-	-	3.0		
			V _{CE} =2V, I _{OUT} =125mA	-	-	5.0		
			V _{CE} =2V, I _{OUT} =200mA	-	-	6.0		
			V _{CE} =2V, I _{OUT} =275mA	-	-	7.0		
V _{CE} =2V, I _{OUT} =350mA	-	-	8.0					
DC Current Transistor Ratio	h _{FE}	2	V _{CE} =2V, I _{OUT} =350mA	1000	-	-		
Clamp Diode Reverse Current	I _E	6	V _R =50V, Ta=25 °C	-	-	50	μ A	
Clamp Diode Forward Voltage	V _F	7	V _R =50V, Ta=85 °C	-	-	100	V	
			I _F =350mA	-	-	2.0		
Input Capacitance	C _{IN}			-	15	-	pF	
Turn-On Delay	t _{ON}	8	V _{OUT} =50V, R _L =163 Ω C _L =15 pF	-	0.1	-	μ S	
Turn-Off Delay	t _{OFF}			-	0.2	-		

TEST CIRCUIT

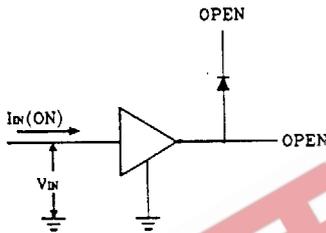
1. I_{CEX}



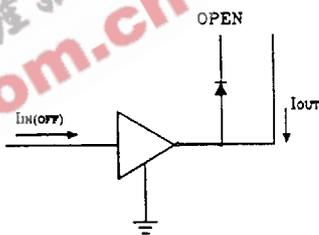
2. $V_{CE(sat)}$, h_{FE}



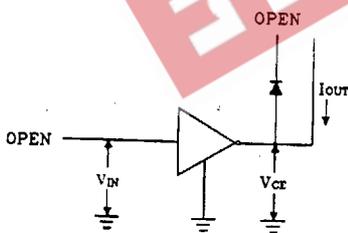
3. $I_{IN(ON)}$



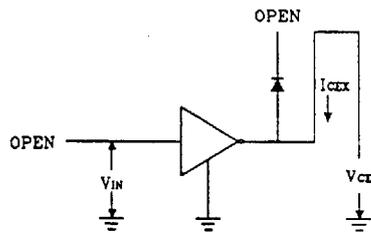
4. $I_{IN(OFF)}$



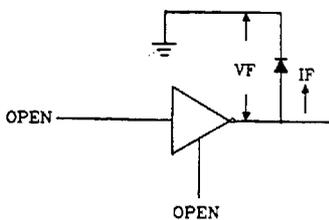
5. $V_{IN(ON)}$



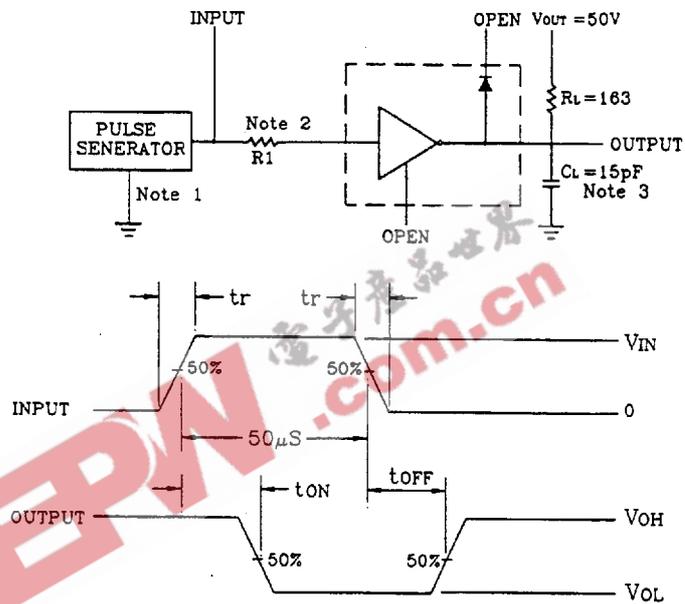
6. I_R



7. V_F



8. t_{ON} , t_{OFF}



Notes: 1. Pulse Width $50\mu s$, Duty Cycle 10%

Output Impedance 50Ω

$t_r \leq 5ns$, $t_f \leq 10ns$

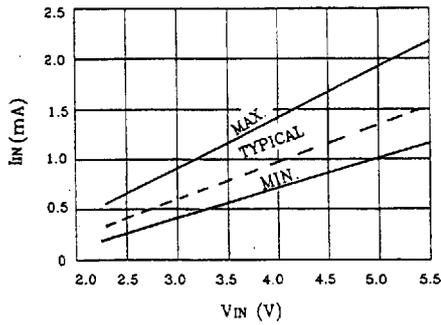
2. See below

Input Conditions

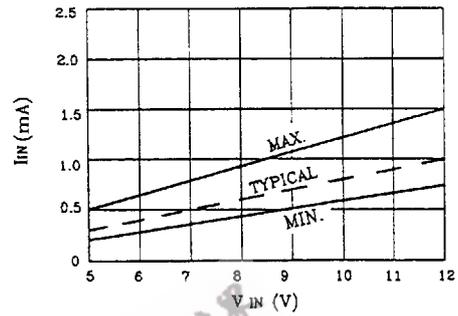
TYPE NUMBER	R_I	V_{IH}
ULN2803	0	3V
ULN2804	0	8V

3. C_L includes prob and jig capacitance.

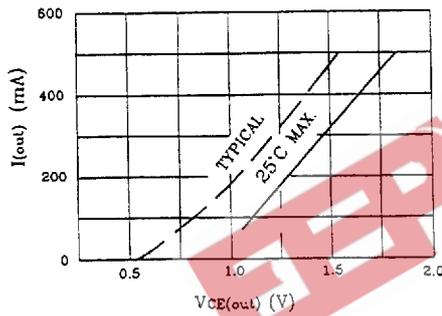
ULN2803 $I_{IN} - V_{IN}$



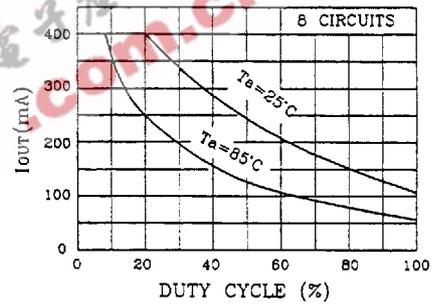
ULN2804 $I_{IN} - V_{IN}$



$F_D - T_a$



$I_{OUT} - V_{CE(out)}$



$I_{OUT} - \text{DUTY CYCLE}$

